

T-79-06-10

SL561B, SL561C

ULTRA LOW NOISE PREAMPLIFIERS

This integrated circuit is a high gain, low noise preamplifier designed for use in audio and video systems at frequencies up to 6MHz. Operation at low frequencies is eased by the small size of the external components and the low 1/f noise. Noise performance is optimised for source impedances between 20Ω and $1k\Omega$ making the device suitable for use with a number of transducers including photo-conductive IR detectors, magnetic tape heads and dynamic microphones.
The SL561B is only available in the TO-5 package.

The SL561C is only available in the Plastic package.

FEATURES

- High Gain
- 60dB
- Low noise
- $0.8 \text{ nV/}/\text{Hz} (\text{Rs} = 50\Omega)$
- Bandwidth
- 6MHz
- Low Power Consumption
- $10 \text{ mW} (V_{cc} = 5 \text{ V})$

APPLICATIONS

- Audio Preamplifiers (low noise from low impedance source)
- Video Preamplifier
- Preamplifier for use in Low Cost Infra-Red Systems

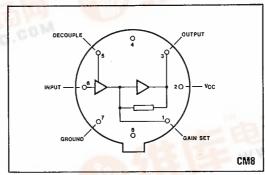


Fig.1 Pin connections (viewed from above) SL561B

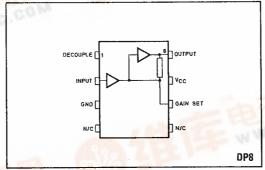


Fig.2 Pin connections (viewed from above) SL561C

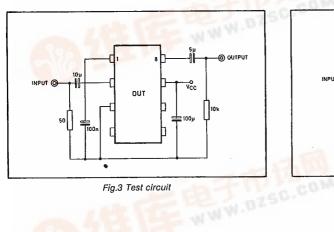


Fig.3 Test circuit

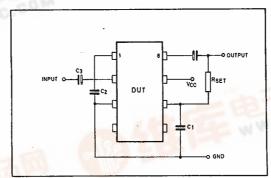


Fig.4 Typical application

ELECTRICAL CHARACTERISTICS PLESSEY SEMICONDUCTORS

Test conditions (unless otherwise stated):

Vcc 5V Source impedance 50Ω Load impedance $10k \Omega$ Tamb 25°C T-79-06-10

SL561B

Characteristic	Value				
	Min.	Тур.	Max.	Units	Conditions
Voltage gain	57	60	63	dB	Pin 1 O/C
Equivalent input noise voltage		0.8	1.2	nV/√Hz	100Hz to 6MHz
Output voltage	2	3		V p-p	See note
Supply current		2.0	3.0	mA	
Output resistance		50		Ω	
Input resistance		3		kΩ	•
Input capacitance		15		pF	
Upper cut-off frequency	5	6.5		MHz	Vout = 10mV p-p
		6.2		MHz	Vout = 1.5V p-p
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SL561C

Characteristic	Value			i		
	Min.	Тур.	Max.	Units	Conditions	
Voltage gain	57	60	63	dB	Pin 6 O/C	
Equivalent input noise voltage		0.8		nV/√Hz	100Hz to 6MHz	
Input resistance		3.		kΩ		
Input capacitance		15	•	pF		
Output impedance		50		Ω		
Output voltage	2	3		V p-p	See note	
Supply current		2	3	mA		
Bandwidth		6		MHz		

OPERATING NOTES (Pin numbers refer to DIL package)

Upper cut-off Frequency

The bandwidth of the amplifier can be reduced from 6MHz to any desired value by a capacitor from pin 6 to ground. This is shown in Fig.5. No degradation in noise or output swing occurs when this capacitor is used. The high frequency roll off is approximately 6dB/octave.

Low frequency response

The capacitors C_2 and C_3 (Fig.4) determine the lower cutoff frequency. C_2 decouples an internal feedback loop and if its value is close to that of C_3 an increase in gain at low frequencies can occur. For a flat response either make C_2 less than 0.05 C_3 or make C_2 greater than 5 C_3 .

Gain set facility

Provision is made to adjust the gain by means of a resistor between pin 6 and the output. Gains as low as 10dB can be selected. This resistor increases the feedback around the output stage and stability problems can result if the bandwidth of the amplifier is not reduced as indicated in Note 1. Fig.6 shows recommended values of C₁ for each gain range. Since the input stage is a common emitter stage without emitter degeneration (for best noise) at values of gain less than 40dB this input stage, rather than the output

stage, determines the maximum output voltage swing. For a distortion of less than 10% the input voltage should be restricted to less than 5mV (see Fig.9).

Driving low impedance loads

The quiescent current of the output emitter follower is 0.5mA. If larger voltage swings are required into low impedance loads this current can be increased by a resistor from pin 8 to ground. To avoid exceeding the ratings of the output transistor the resistor should not be less than 200Ω .

Noise performance

The equivalent input voltage for the amplifier is shown in Fig.7 From this the input noise voltage and current generators can be derived. They are:

 $e_n = 0.8 \text{nV}/\sqrt{\text{Hz}}$

 $in = 2.0pA/\sqrt{Hz}$

Flicker or 1/f noise is not normally a problem, the knee frequency being typically below 100Hz.

ABSOLUTE MAXIMUM RATINGS

Supply voltage	10V
Storage temperature range	-55°C to +125°C
Operating temperature range DIL	-55°C to +100°C
Operating temperature range TO5	-55°C to +125°C

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PLESSEY SEMICONDUCTORS

19E 0 3550273 000333 5

SL561B/C

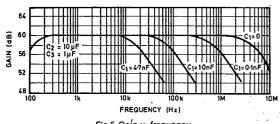


Fig.5 Gain v. frequency

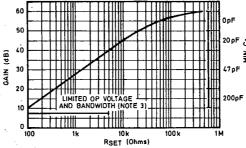


Fig.6 Gain v. Rset

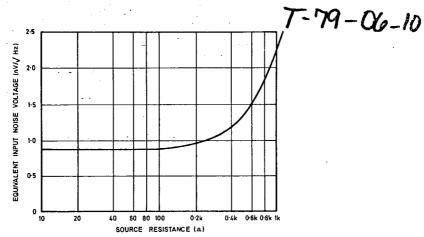


Fig.7 Noise v. source impedance

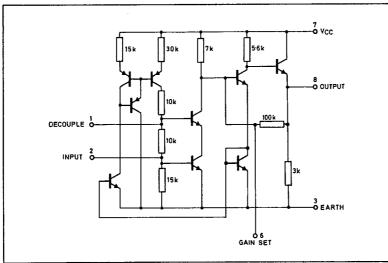


Fig.8 Circuit diagram

12E D 7220513 0007774 4

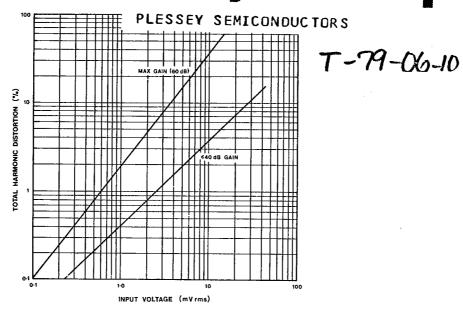


Fig.9 Harmonic distortion SL561 at 20kHz